



## Linear Systems PNP Transistor

The LS3550SA is a PNP transistor mounted in a SOT-23 package.
The SOT-23 provides ease of manufacturing.
(See Packaging Information).
<b>LS3550SA Features:</b>
<ul style="list-style-type: none"> <li>▪ Low Output Capacitance</li> </ul>

### FEATURES

3 LEAD SOT-23 SURFACE MOUNT PACKAGE

### ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

@ 25°C (unless otherwise noted)

### Maximum Temperatures

Storage Temperature	-65°C to +150°C
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Operating Junction Temperature	-55°C to +150°C
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### Maximum Power Dissipation

Continuous Power Dissipation	TBD
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### Maximum Currents

Collector Current	10mA
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### Maximum Voltages

Collector to Collector Voltage	80V
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### ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTICS	MIN.	TYP.	MAX.	UNITS	CONDITIONS
$BV_{CBO}$	Collector to Base Voltage	-45	--	--	V	$I_C = 10\mu A, I_E = 0$
$BV_{CEO}$	Collector to Emitter Voltage	-45	--	--	V	$I_C = 10\mu A, I_B = 0$
$BV_{EBO}$	Emitter-Base Breakdown Voltage	-6.2	--	--	V	$I_E = 10\mu A, I_C = 0^2$
$BV_{CCO}$	Collector to Collector Voltage	-80	--	--	V	$I_C = 10\mu A, I_E = 0$
$h_{FE}$	DC Current Gain	150	--	--		$I_C = -1mA, V_{CE} = -5V$
		120	--	--		$I_C = -10mA, V_{CE} = -5V$
		100	--	--		$I_C = -100mA, V_{CE} = -5V$
$V_{CE(SAT)}$	Collector Saturation Voltage	--	--	-0.25	V	$I_C = -100mA, I_B = -10mA$
$I_{EBO}$	Emitter Cutoff Current	--	--	-0.2	nA	$I_E = 0, V_{CB} = -3V$
$I_{CBO}$	Collector Cutoff Current	--	--	-0.2	nA	$I_E = 0, V_{CB} = -30V$
$C_{OBO}$	Output Capacitance	--	--	2	pF	$I_E = 0, V_{CB} = -10V$
$f_T$	Current Gain Bandwidth Product(Current)	--	--	600	MHz	$I_C = -1mA, V_{CE} = -5V$
NF	Narrow Band Noise Figure	--	--	3	dB	$I_C = -100\mu A, V_{CE} = -5V, BW=200Hz, R_G = 10\Omega, f = 1KHz$

Notes:

1. Absolute Maximum ratings are limiting values above which serviceability may be impaired
2. The reverse base-to-emitter voltage must never exceed 6.2 volts; the reverse base-to-emitter current must never exceed 10μA.



Available Packages:

LS3550SA in SOT-23

LS3550SA available as bare die

Please contact Micross for full package and die dimensions:

Email: [chipcomponents@micross.com](mailto:chipcomponents@micross.com)

Web: [www.micross.com/distribution.aspx](http://www.micross.com/distribution.aspx)

SOT-23 (Top View)

